

The RF Sub-Micron MOSFET Line RF Power Field Effect Transistors N-Channel Enhancement-Mode Lateral MOSFETs, MOSFET 30W RF PWR FET NI-360L

Manufacturers	NXP Semiconductor
Package/Case	NI-360-3
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for MRF9030LR1 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

MRF9030LR1 is a high-power, high-frequency RF transistor that is commonly used in radio frequency (RF) amplifier applications. It is manufactured by NXP Semiconductors, a company that specializes in designing and producing high-performance electronic components.

Features

Operating frequency range of 860 to 960 MHz

High gain and efficiency

30 W output power

Designed for use in Class AB and Class C amplifiers

Suitable for use in a range of applications, including wireless communication systems, broadcasting, and radar systems.

Application

BLF6G22LS-160B

BLY93B

MRF9030LR5

MRFE6VP61K25H

SD2933

STAC2942B-3





Related Products



[MRF6S9125NR1](#)

NXP Semiconductor
TO-270



[MRF8P20100HSR3](#)

NXP Semiconductor
NI-780S-4



[MRF6VP2600HR6](#)

NXP Semiconductor
NI-1230



[MRF6VP2600H](#)

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[MRF6S20010GNR1](#)

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TO-270



[MRF8P20160HSR3](#)

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NI-780S-4



[MRF6V2300NBR1](#)

NXP Semiconductor
TO-272



[MRF374A](#)

NXP Semiconductor
NI-650

